

4GBJ20005 THRU 4GBJ2010

| Glass Passivated Bridge Rectifiers | | | Reverse Voltage - 50 to 1000 Volts Forward Current - 20 Amperes | | | | | | |
|---|------------------|--|--|--------------|--------------|--|--------------|--|------------------|
| | | FOrw | ard C | Jurrei | it - 2 | U AM | peres | | |
| Features • Glass passivated chip • Low forward voltage drop • Ideal for printed circuit board • High surge current capability •Meet UL flammability classification 94V-0 | | 4GE | 3J | .995 (25 | .3) | • | - | C | RoHS OMPLIANT |
| Mechanical Data Polarity: Symbol marked on body Mounting position: Any Note: Products with logo or how or how or are made by HY Electronic (Cayman) Limited. Applications General purpose use in AC/DC bridge full wave rectification, for SMPS, lighting ballaster, adapter, etc. | | | 1.45) 1.05) (2.1) (1.7) 3 (1.1) 5 (0.9) .303 | | | 150 (38) 157 157 (130) (130) (130) (130) (130) (151) (130) (130) (130) (130) (152) (130) (170) (170) (170) | 382 (9.7) | 150 (3.8) 134 (3.4) 150 (2.5) 150 (2.5) 150 (2.5) 150 (2.5) 150 (2.5) 150 (2.5) 150 (2.5) 150 (2.5) 150 (2.5) 098 (2.5) |)))) |
| | | Package Outline Dimensions in Inches (Millimet | | | | | | | ers) |
| Maximum Ratings and Electrical Characteristics | | | | | | | | | |
| Rating at 25 $^\circ C$ ambient temperature unless otherwise specified. | | | | | | | | | |
| Single phase, half wave, 60Hz, resistive or inductive load. | | | | | | | | | |
| For capacitive load, derate current by 20%. | | | | | | | | | |
| Characteristics | Symbol | 4GBJ 20005 | 4GBJ 2001 | 4GBJ 2002 | 4GBJ 2004 | 4GBJ 2006 | 4GBJ 2008 | 4GBJ 2010 | Unit |
| Maximum Repetitive Peak Reverse Voltage | Vrrm | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS Voltage | Vrms | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | Vdc | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum Average Forward (with heatsink Note 2) | Icon | | | 20.0 | | | | | |
| Rectified Current @ Tc=100°C (without heatsink) | I(AV) | 4.1 | | | | | | A | |
| Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, | IFSM | 260 | | | | | | | А |
| Superimposed on Rated Load (JEDEC Method) | IFSM | | | | | | | ~ | |
| I ² t Rating for Fusing (t<8.3mS) | l ² t | 280.5 | | | | | | | A ² s |
| Peak Forward Voltage per Diode at10A DC | Vf | 1.0 | | | | | | | V |
| Maximum DC Reverse Current at Rated @Tj=25°C | lr | 5.0 500 | | | | | | | μA |
| DC Blocking Voltage per Diode $@T_{J}=125^{\circ}C$ | ii. | | | | | | | | |
| Typical Junction Capacitance per Diode (Note1) | CJ | 60 | | | | | | | pF |
| Typical Thermal Resistance to case (Note2) | Rejc | 0.93 | | | | | | | |
| Operating Junction Temperature Range | TJ | | | -{ | 55 to +15 | 50 | | | °C |

Storage Temperature Range

Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2.Device mounted on 300mm*300mm*1.6mm Cu plate heatsink.

3. The typical data above is for reference only

4GBJ20*-U-00-00 Rev. 11, 18-May-2020

 $^{\circ}\!\mathrm{C}$

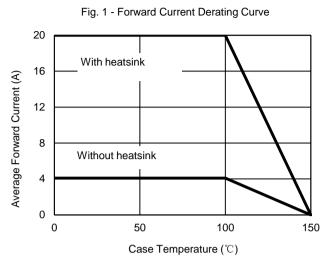
-55 to +150

Tstg

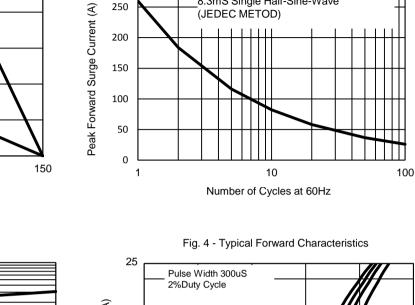
Rating and Characteristic Curves 4GBJ20005 THRU 4GBJ2010

1000









300

250

200

Fig. 2 - Maximum Non-Repetitive Surge Current

8.3mS Single Half-Sine-Wave

(JEDEC METOD)

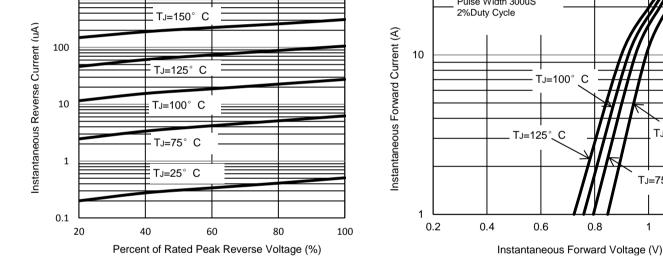
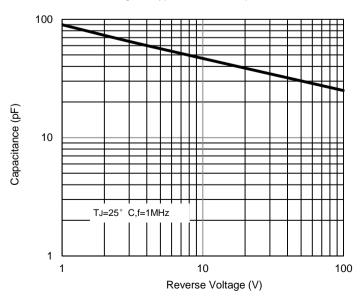


Fig. 5 - Typical Junction Capacitance



The curve above is for reference only.

4GBJ20*-U-00-00 Rev. 11, 18-May-2020

TJ=25°

1.2

TJ=75°

1

Disclaimer

ALL specifications and data are subject to be changed without notice to improve reliability function or design or other reasons.

HY makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the cotinuing production of any product. To the maximum extent permitted by applicable law, HY disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on HY's knowledge of typical requirements that are often placed on HY products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application.Parameters provided in datasheets and specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify HY's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, HY products are not designed for use in medical, life-saving, or life-sustaining applications or for any other applications in which the failure of the HY product could result in personal injury or death. Customers using or selling HY products not expressly indicated for use in such applications do so at their own risk.Please contact authorized HY personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of HY. Product names and markings noted herein may be trademarks of their respective owners.